TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSVI-H)

# **TPCA8052-H**

Switching Regulator Applications
Motor Drive Applications
DC-DC Converter Applications

- · Small footprint due to a small and thin package
- · High-speed switching
- Small gate charge: Q<sub>SW</sub> = 6.8 nC (typ.)
- Low drain-source ON-resistance:  $R_{DS\ (ON)}$  = 7.2  $m\Omega\ (typ.)$
- High forward transfer admittance: |Y<sub>fs</sub>| = 58 S (typ.)
- Low leakage current:  $I_{DSS}$  = 10  $\mu$ A (max) ( $V_{DS}$  = 40 V)
- Enhancement mode:  $V_{th}$  = 1.3 to 2.3 V ( $V_{DS}$  = 10 V,  $I_D$  = 0.2 mA)

### **Absolute Maximum Ratings (Ta = 25°C)**

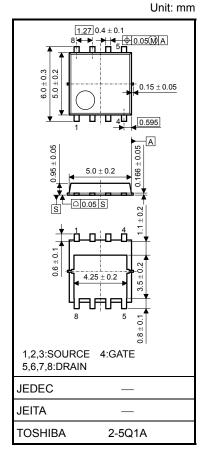
Characte	eristic	Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	40	V	
Drain-gate voltage (F	$R_{GS} = 20 \text{ k}\Omega$ )	$V_{DGR}$	40	٧	
Gate-source voltage		$V_{GSS}$	±20	V	
Drain current	DC (Note 1)	ΙD	20	Α	
Drain current	Pulsed (Note 1)	I <sub>DP</sub>	60		
Drain power dissipati	on (Tc = 25°C)	$P_{D}$	30	W	
Drain power dissipati	on (t = 10 s) (Note 2a)	$P_{D}$	2.8	W	
Drain power dissipati	on (t = 10 s) (Note 2b)	PD	1.6	W	
Single-pulse avalanc	he energy (Note 3)	EAS	37	mJ	
Avalanche current		I <sub>AR</sub>	20	Α	
Repetitive avalanche	energy c = 25°C) (Note 4)	E <sub>AR</sub>	2.24	mJ	
Channel temperature	!	T <sub>ch</sub>	150	°C	
Storage temperature	Storage temperature range		-55 to 150	°C	

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

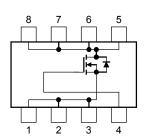
operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.069 g (typ.)

#### **Circuit Configuration**

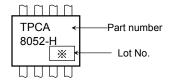




#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R <sub>th (ch-c)</sub>	4.17	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	78.1	°C/W

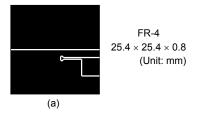
## Marking (Note 5)

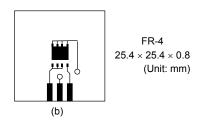


Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)

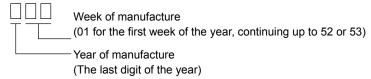




Note 3:  $V_{DD} = 24~V,~T_{ch} = 25~^{\circ}C$  (initial), L = 100  $\mu H,~R_G = 25~\Omega,~I_{AR} = 20~A$ 

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: \* Weekly code: (Three digits)



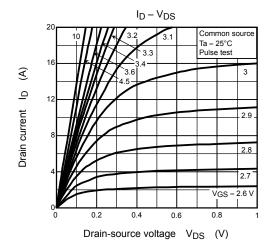


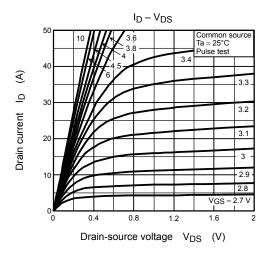
# **Electrical Characteristics (Ta = 25°C)**

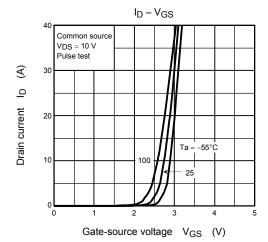
Ch	naracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cui	rrent	I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	ent	I <sub>DSS</sub>	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V	_	_	10	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10$ mA, $V_{GS} = 0$ V	40	_	_	V
Diain-source bre	akuowii voitage	V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	23	_	_	·
Gate threshold v	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, I_D = 0.2 \text{ mA}$	1.3	_	2.3	V
Drain-source ON	rocistanoo	Pro (ON)	$V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$	_	9.1	13.1	- mΩ
Diain-source On	-resistance	R <sub>DS</sub> (ON)	$V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$	_	7.2	11.3	11152
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, I_{D} = 10 \text{ A}$	29	58	_	S
Input capacitance	е	C <sub>iss</sub>		_	1620	2110	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	85	130	pF
Output capacitance		C <sub>oss</sub>		_	280	_	
Gate resistance		rg	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 5 \text{ MHz}$		2.3	3.5	Ω
Switching time	Rise time	t <sub>r</sub>	ACS 0 A 10 A 10 E 10 V A 10 V	_	2.4	_	- ns
	Turn-on time	t <sub>on</sub>			8.4	_	
	Fall time	t <sub>f</sub>			8.0	_	
	Turn-off time	t <sub>off</sub>	$V_{DD} \approx 20 \text{ V}$ Duty $\leq$ 1%, $t_W = 10 \mu\text{s}$	_	35	_	
Total gate charge	gate charge		$V_{DD} \approx 32 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	_	25	_	
(gate-source plus		Qg	$V_{DD} \approx 32 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 20 \text{ A}$	_	_ 13		
Gate-source charge 1		Q <sub>gs1</sub>	$V_{DD} \approx 32 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 20 \text{ A}$	_	5.6	_	nC
Gate-drain ("Miller") charge		Q <sub>gd</sub>		_	3.8	_	
Gate switch char	ge	Q <sub>SW</sub>			6.8		

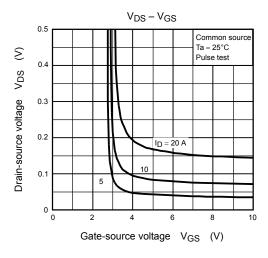
# Source-Drain Ratings and Characteristics (Ta = 25°C)

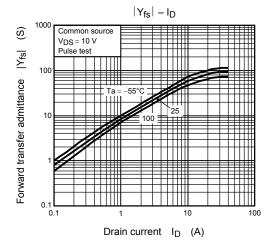
Characteri	stic		Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse	(Note 1)	I <sub>DRP</sub>	_	_	_	60	Α
Forward voltage (diode)			V <sub>DSF</sub>	I <sub>DR</sub> = 20 A, V <sub>GS</sub> = 0 V	_	_	-1.2	V

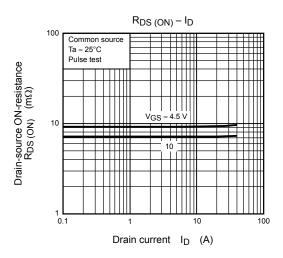




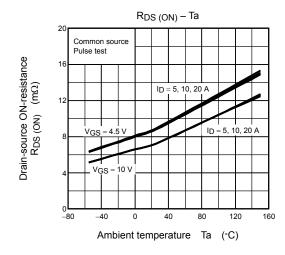


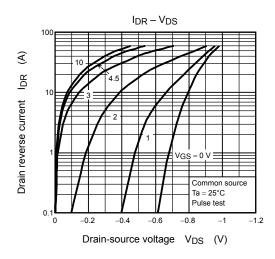


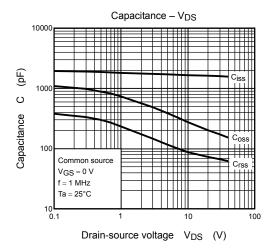


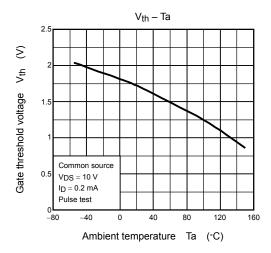


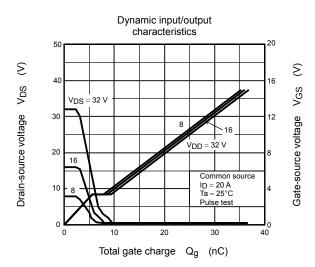
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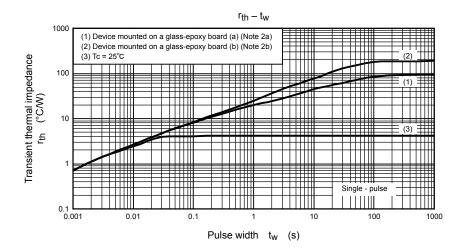


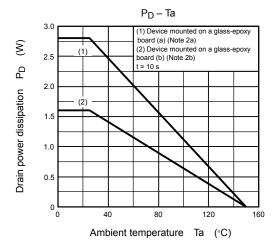


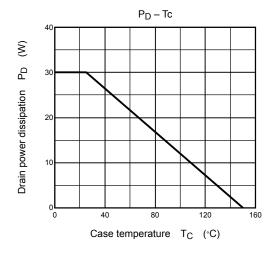


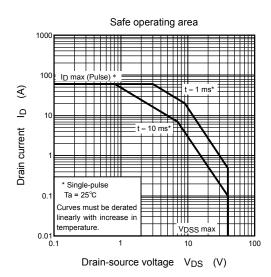


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